# **BOURNS®**

- Designed for Complementary Use with TIP125, TIP126 and TIP127
- 65 W at 25°C Case Temperature
- 5 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 1000 at 3 V, 3 A

This series is obsolete and not recommended for new designs.

# B 1 2 3

Pin 2 is in electrical contact with the mounting base.

MDTRACA

# absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	TIP120		60	
Collector-base voltage (I <sub>E</sub> = 0)	TIP121	V <sub>CBO</sub>	80	V
	TIP122		100	
	TIP120		60	
Collector-emitter voltage (I <sub>B</sub> = 0)	TIP121	VCEO	80	V
	TIP122		100	
Emitter-base voltage		V <sub>EBO</sub>	5	V
Continuous collector current		I <sub>C</sub>	5	Α
Peak collector current (see Note 1)		I <sub>CM</sub>	8	Α
Continuous base current		I <sub>B</sub>	0.1	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P <sub>tot</sub>	65	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note	3)	P <sub>tot</sub>	2	W
Unclamped inductive load energy (see Note 4)		½LI <sub>C</sub> <sup>2</sup>	50	mJ
Operating junction temperature range		T <sub>j</sub>	-65 to +150	°C
Storage temperature range		T <sub>stg</sub>	-65 to +150	ç
Lead temperature 3.2 mm from case for 10 seconds			260	ç

NOTES: 1. This value applies for  $t_p \le 0.3$  ms, duty cycle  $\le 10\%$ .

- 2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 5 mA,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



# electrical characteristics at 25°C case temperatur e

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
Collector-emitter			TIP120	60				
V <sub>(BR)CEO</sub>	breakdown voltage	$I_C = 30 \text{ mA}$	$I_B = 0$	TIP121	80			V
	breakdown voltage	(see Note 5)		TIP122	100			
	Collector-emitter	V <sub>CE</sub> = 30 V	I <sub>B</sub> = 0	TIP120			0.5	
I <sub>CEO</sub>	cut-off current	$V_{CE} = 40 \text{ V}$	$I_B = 0$	TIP121			0.5	mA
	cut-on current	$V_{CE} = 50 \text{ V}$	$I_B = 0$	TIP122			0.5	
	Collector cut-off	V <sub>CB</sub> = 60 V	I <sub>E</sub> = 0	TIP120			0.2	
I <sub>CBO</sub>	current	V <sub>CB</sub> = 80 V	$I_E = 0$	TIP121			0.2	mA
	current	V <sub>CB</sub> = 100 V	$I_E = 0$	TIP122			0.2	
I <sub>EBO</sub>	Emitter cut-off	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0				2	mA
,EBO	current	AER - O.	.C = 0				-	1111
h <sub>FE</sub>	Forward current	$V_{CE} = 3 V$	$I_C = 0.5 A$	(see Notes 5 and 6)	1000			
"FE	transfer ratio	$V_{CE} = 3 V$	$I_C = 3 A$		1000			
V <sub>CE(sat)</sub>	Collector-emitter	I <sub>B</sub> = 12 mA	$I_C = 3 A$	(see Notes 5 and 6)			2	V
*CE(sat)	saturation voltage	$I_B = 20 \text{ mA}$	$I_C = 5 A$	(occ Notes o and o)			4	·
$V_{BE}$	Base-emitter	V <sub>CE</sub> = 3 V	I <sub>C</sub> = 3 A	(see Notes 5 and 6)			2.5	V
• BE	voltage	VOE - 3V	i( = 071	(000 110100 0 and 0)			2.0	•
V <sub>EC</sub>	Parallel diode	I <sub>E</sub> = 5 A	I <sub>B</sub> = 0	(see Notes 5 and 6)			3.5	V
*EC	forward voltage	'E - 3 A	ı <sup>R</sup> – ∧	(SCC NOICS S and C)	13.		5.5	•

NOTES: 5. These parameters must be measured using pulse techniques,  $t_0 = 300 \,\mu s$ , duty cycle  $\leq 2\%$ .

#### thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
R <sub>0JC</sub> Junction to case thermal resistance			1.92	°C/W
R <sub>0JA</sub> Junction to free air thermal resistance			62.5	°C/W

# resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS †		MIN	TYP	MAX	UNIT	
t <sub>on</sub> Turn-on time	I <sub>C</sub> = 3 A	$I_{B(on)} = 12 \text{ mA}$	$I_{B(off)} = -12 \text{ mA}$		1.5		μs
t <sub>off</sub> Turn-off time	$V_{BE(off)} = -5 V$	$R_L = 10 \Omega$	$t_p = 20 \ \mu s, \ dc \le 2\%$		8.5		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### TYPICAL CHARACTERISTICS

# **TYPICAL DC CURRENT GAIN** vs **COLLECTOR CURRENT** TCS120AA 40000 $T_c = -40^{\circ}C$ 25°C T<sub>C</sub> = 100°C h<sub>FE</sub> - Typical DC Current Gain 10000 1000 3 V = 300 µs, duty cycle < 2% 100 0.5 1.0 5.0 Ic - Collector Current - A

#### Figure 1.

# COLLECTOR-EMITTER SATURATION VOLTAGE

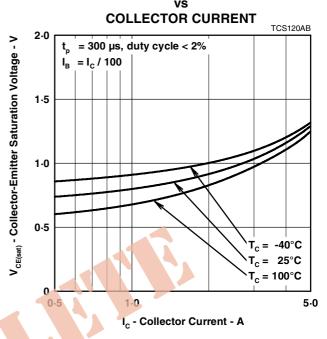
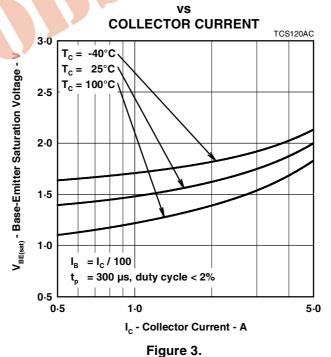


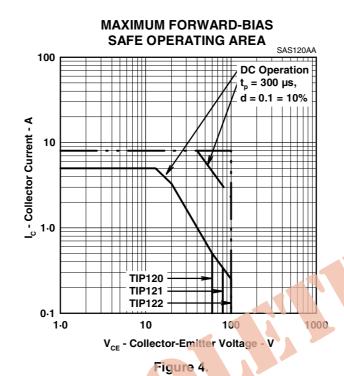
Figure 2.

#### BASE-EMITTER SATURATION VOLTAGE



#### PRODUCT INFORMATION

## **MAXIMUM SAFE OPERATING REGIONS**



## THERMAL INFORMATION

## MAXIMUM POWER DISSIPATION

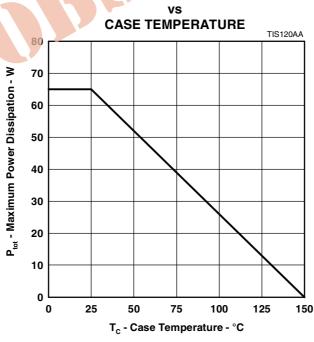


Figure 5.

## PRODUCT INFORMATION